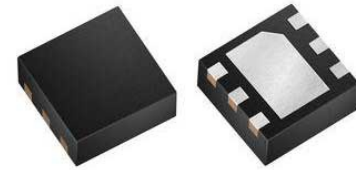


Power MOSFET, MOSFET PFET 2X2 20V 4.1A 106MOHM

Manufacturers	ON Semiconductor, LLC
Package/Case	DFN-6, 2 x 2
Product Type	Transistors
RoHS	Rohs
Lifecycle	



Images are for reference only

Please submit RFQ for NTLJD3115PT1G or [Email to us: sales@ovaga.com](mailto:sales@ovaga.com) We will contact you in 12 hours.

[RFQ](#)

General Description

Power MOSFET -20 V, -4.1 A, μ Cool™ Dual P-Channel, 2x2 mm WDFN Package

Features

WDFN Package Provides Exposed Drain Pad for Excellent Thermal Conduction

2x2 mm Footprint Same as SC-88

Lowest RDS(on) Solution in 2x2 mm Package

1.8 V RDS(on) Rating for Operation at Low Voltage Gate Drive Logic Level

Low Profile (< 0.8 mm) for Easy Fit in Thin Environments

Bidirectional Current Flow with Common Source Configuration

Application

ONSEMI

Related Products



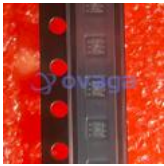
[NTR4003NT3G](#)

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[NTZD3155CT2G](#)

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[NTMFS4C10NT1G](#)

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[NTHD4102PT1G](#)

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ChipFET-8



[NTH4L020N120SC1](#)

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TO-247